

INF5490 RF MEMS

LN01: Introduction. MEMS in RF

Spring 2010, Oddvar Søråsen
Department of informatics, UoO

Today's lecture

- Background for the course INF5490/9490
- Course plan spring 2010
- Introduction
 - MEMS in general
 - RF systems
 - MEMS in RF systems

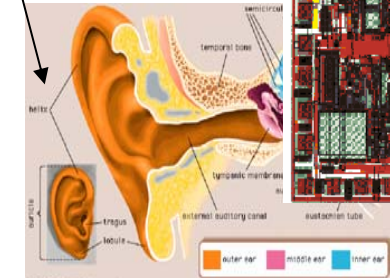
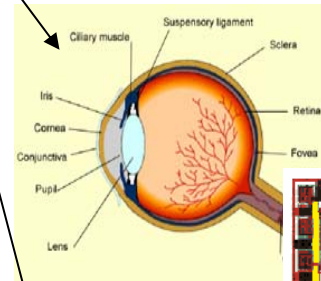
INF5490 RF MEMS

- **MEMS** (Micro Electro **Mechanical** Systems)
 - A relatively new research activity in the NANO group
 - NANO competence: Design of mico/nano- electronic systems: modeling, analysis and implementation of analog and digital VLSI circuits and systems
- Activity inspired by:
 - **National focus** on micro- and nano-technology
 - The Research Council of Norway
 - **MiNaLab** (Micro Nano Technology-lab), next-door
 - SINTEF lab
 - UiO lab

Why MEMS in the Nano-group?

- New possibilities to implement **integrated, miniaturized systems**
 - Electronic systems integrating MEMS give a new **degree of freedom** for designers
 - **A.** May integrate micro **mechanical** components in the systems: add: "eyes, ears, hands"
 - **B.** MEMS – components need **interfacing** electronics!

MEMS



Electronics

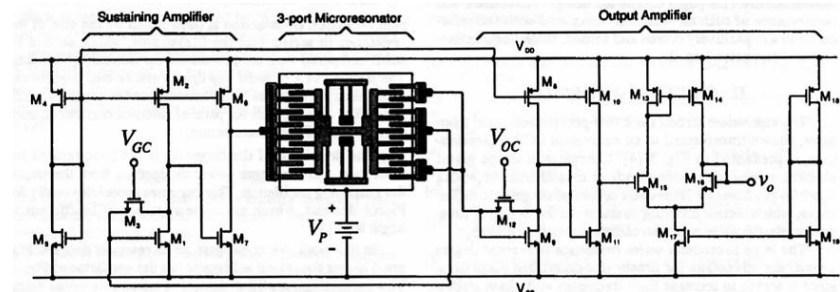
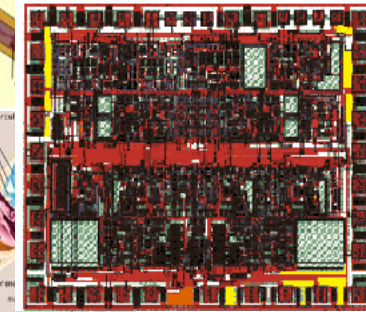
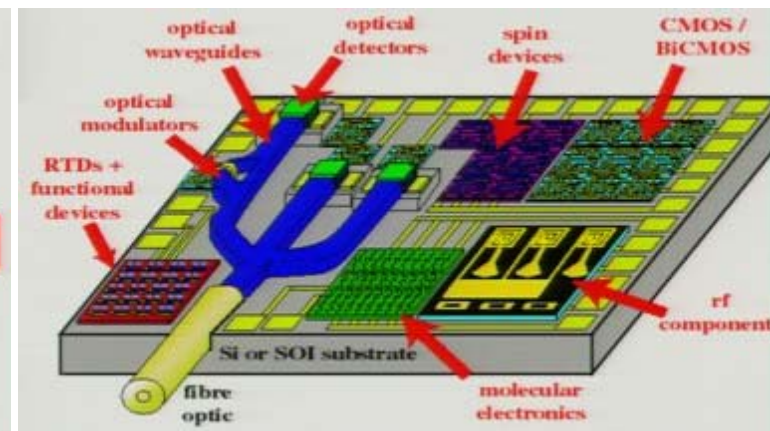
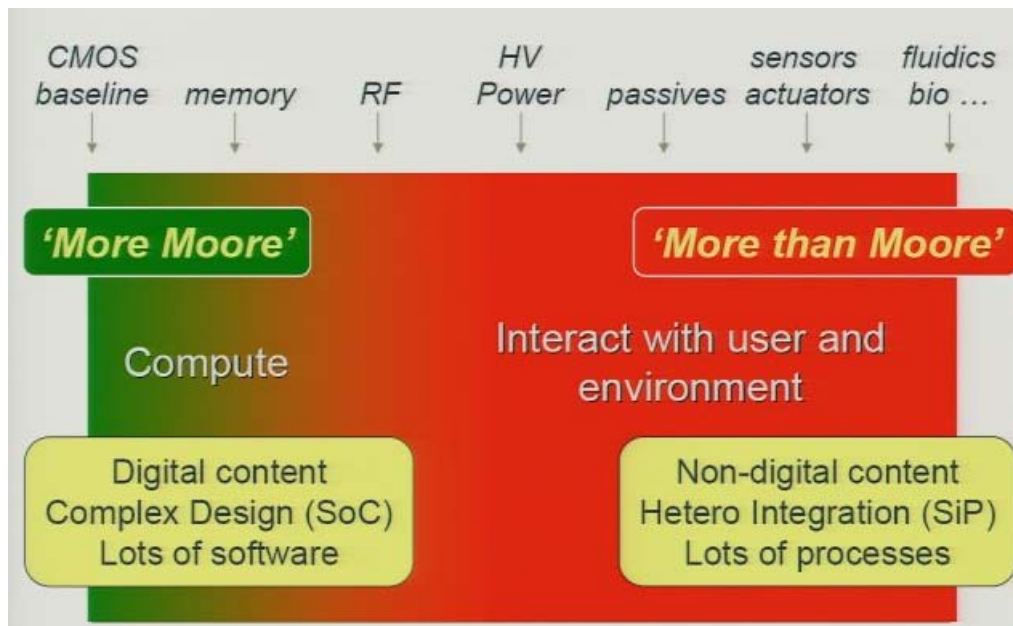
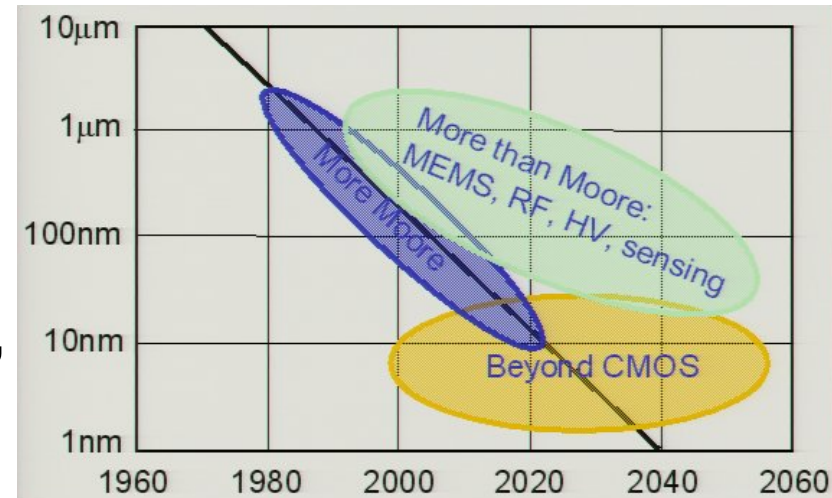


Fig. 4: Circuit schematic for the microresonator oscillator.

Interfacing to the "real world"

- Enhancing "More Moore" by "non-classical" electronic components
- Achieve "Ambient Intelligence" by "More than Moore"



Personal competence

- Physics → modeling and design of VLSI → system design → computer architecture/multiprocessors → **RF MEMS, CMOS-MEMS cointegration**
- Sabbatical at SINTEF MiNaLab 03/04
- Literature studies
- Seminars
 - RF MEMS-seminar by A.M. Ionescu, EPFL, at KTH H04
 - Arr: FSRM, Swiss Foundation for Research in Microtechnology
 - RF MEMS tutorial: G.M. Rebeiz, UCSD, in Tønsberg H05
 - Arr: IMAPS Nordic Conference
 - Workshop on MEMS, IMEC, Leuven, H07
 - Arr: Europractice/STIMESI
 - Course on Cofabrication of MEMS and CMOS, IMEC, Leuven, H08
 - Tutorials and conference: Eurosensors XXIII, Lausanne, H09
- Visiting UC Berkeley and Carnegie Mellon University, H06
 - C.T.-C. Nguyen, G.K. Fedder ++
- Using the simulation package CoventorWare
- Supervising students in relevant fields (Master, Ph.D.)
- Research activity

Selecting a focus → RF MEMS

- MEMS is a broad field of research
 - A focus is needed → RF MEMS
 - Cofabrication of MEMS and CMOS
- ***”RF MEMS refers to the design and fabrication of dedicated MEMS for RF (integrated) circuits”***
 - 1a) Components **operate** micromechanical
and/or
 - 1b) Components **fabricated** using micromachining
 - 2) Components are used in **RF systems**

Some arguments for an RF MEMS activity in the NANO group

- Challenging, promising and exciting field!
- Close connection to the basic competence in circuit technology
- The course fits well into the NANO Master/PhD education
- Actual theme
 - Increasing interest internationally for using MEMS in RF systems
- Large market: **wireless communication**
 - Tele communication, mobile business
 - **Wireless Sensor Networks (WSNs)**
 - Distributed intelligence (observation, actuation)
 - Environmental surveillance, – sensor nodes
 - Ambient Intelligence: - units everywhere!
 - Patient surveillance, - medical implants
 - "Internet of things"
- Growing commercial attention
- Basis for establishing new enterprises

International activity

- RF MEMS is in focus on leading international conferences
 - ISSCC, IEDM (Int. Electron Devices Meeting), Eurosensors
 - MEMS-conferences and journals
 - See NANO web-page!
- *Europractice* and *CMP* offer MPW (Multi Project Wafer)
- Increased industry attention and support of RF MEMS
 - Great potential
 - Miniaturization, increased performance, volume production
 - **BUT MEMS in general is not yet a big hit!**
 - **A few successes: airbag sensor, projector**

RF MEMS: where should I look for?

Top authors, books and web pages

RF MEMS

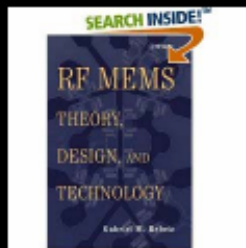
- Clark Nguyen

<http://www.eecs.berkeley.edu/~ctnguyen/>

RF MEMS

- Gabriel Rebeitz

RF MEMS: Theory, Design, and Technology, Wiley, 2003.



NEMS

- Michael Roukes

<http://nano.caltech.edu/>

Adrian M. Ionescu



Nanoscale Systems:

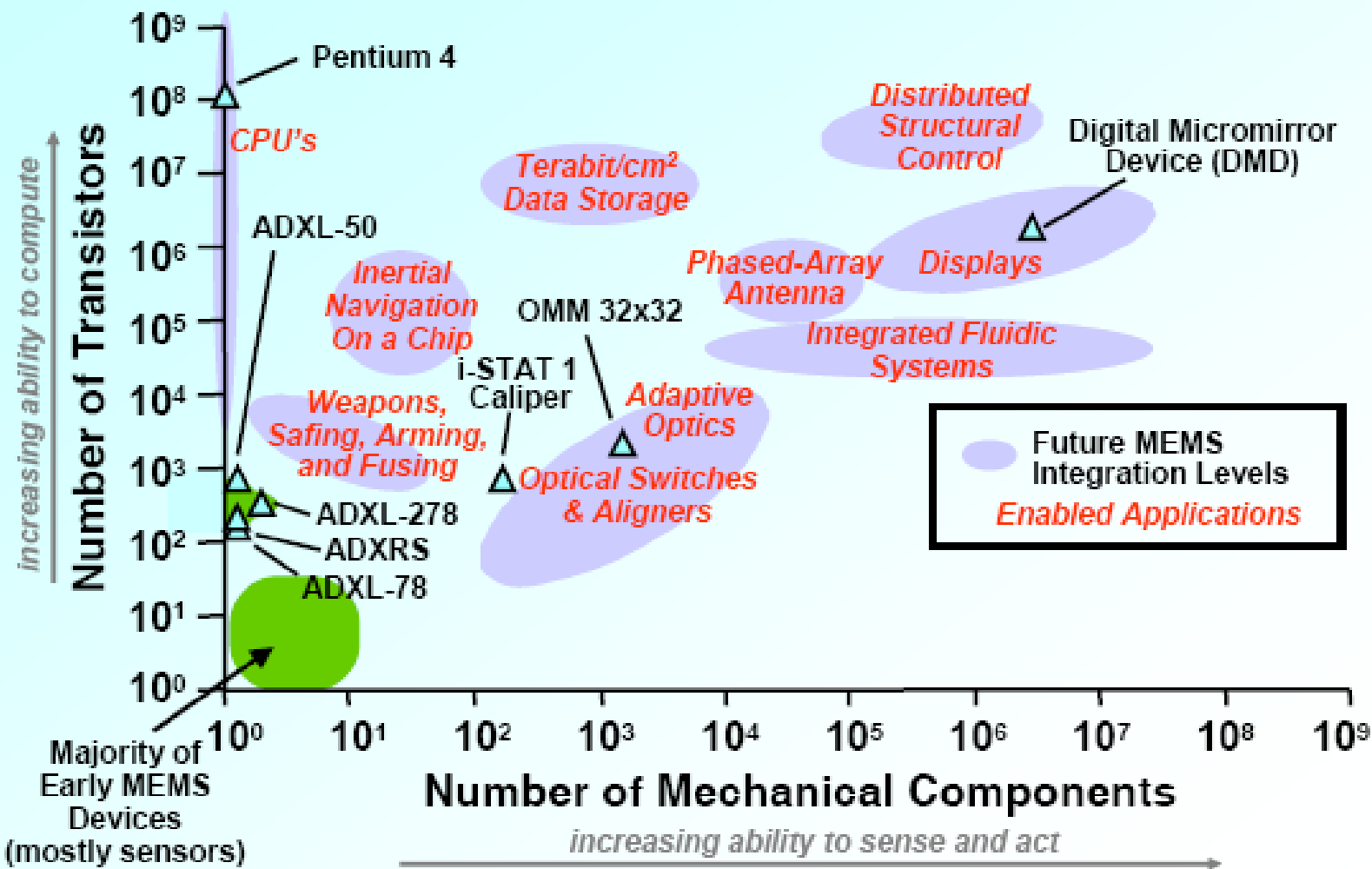
Fundamental & Device Nano-Physics, Bio/Medical Applications, Very-Large-Scale Integration

- [Home](#)
- [People](#)
- [Projects](#)
- [Publications](#)
- [Links](#)

We are working to explore new physics at the nanoscale, and to apply this knowledge to realizing advanced tools for the biomedical and life sciences. Our group's efforts span from very systematic nanoscale engineering for practical applications, to biological investigations enabled by novel devices, to quantum measurements with nanosystems at ultralow temperatures.

Our efforts are part of the [Kavli Nanoscience Institute \(KNI\)](#) at Caltech. Through generous support from both the Gordon and Betty Moore Foundation and the Kavli Foundation, the Caltech "nanoscience community" has been able to assemble state-of-the-art nanofabrication facilities that now enable our work. These facilities include capabilities for 150mm wafer-scale patterning of complex nanodevices with dimensions down to the ten nanometer regime.

Technology Trend and Roadmap for MEMS



Today's lecture

- Background for course INF5490
- Course plan spring 2010
- Introduction
 - MEMS in general
 - RF-systems
 - MEMS in RF-systems

Information about course INF5490

- Course homepage:
 - <http://www.uio.no/studier/emner/matnat/ifi/INF5490/v10/>
 - Messages posted there! **CHECK regularly!**
- Weekly **lectures**: Oddvar Søråsen
 - Thursday 10:15 – 12 in 3B
 - Detailed lectureplan on web
 - Lecture notes will be posted on web before lecture (pdf)
- Language: English

Group assignments

- **Class assignment:** Dag Halfdan Bryn
 - "Felles gruppe" – consult web for weekly plan!
 - Tuesday 14:15 – 16 in 3B
 - First time 26/1
 - Presenting plan and topics for "obliger"
 - Presenting supporting literature
 - Work through assignments
 - Posted a week before
 - Practical aspects
 - Questions, discussion

Obliger

- **2 “obliger”** have to be done
 - Must hand in 2 reports at specified dates (see web)
 - **General guidelines available on web!**
 - **Approval** required for taking the exam
 - Each group consists of 2 students that collaborate
- Topics: micromechanical resonators and filters
 - Simulations using **CoventorWare**
 - 3-dim modeling, FEM-analysis (Finite-Element-Method)
 - High-level modeling, ARCHITECT

CoventorWare

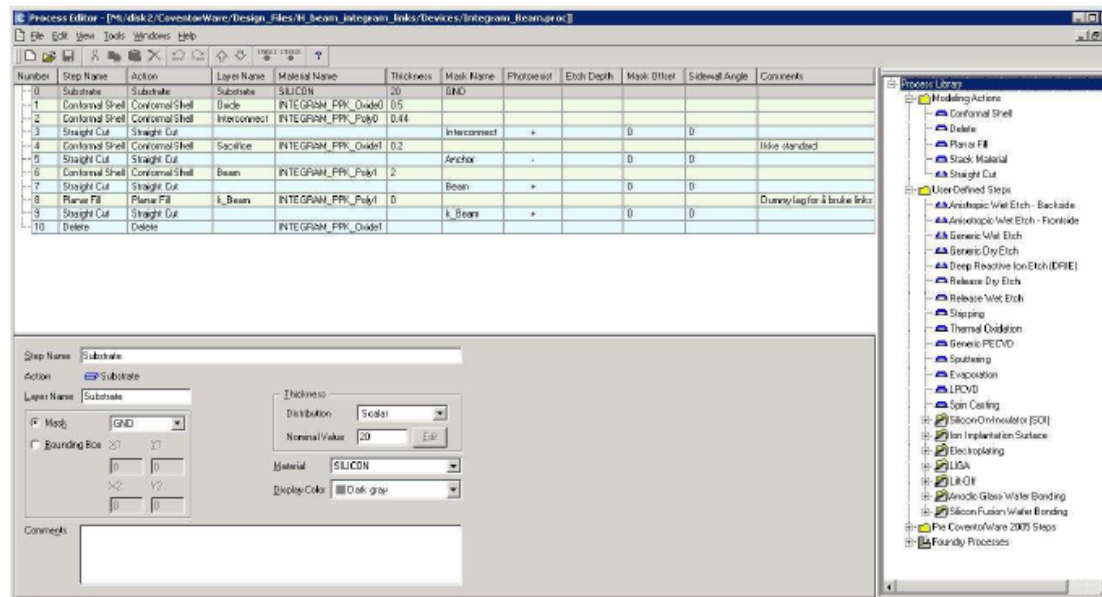
- “State-of-the-art” tool for FEM analysis
 - ”Finite-Element-Method”
- **“Bottom-up” prosedyre:**
 - 1) Build a 3D -model
 - Multiple layers: structural and sacrificial layers
 - Etching pattern, remove sacrificial layer
 - 2) Meshing
 - Tetrahedral, “Manhattan bricks”
 - 3) Solvers
 - Electrical/ mechanical/ coupled
 - Iterate!

COVENTOR

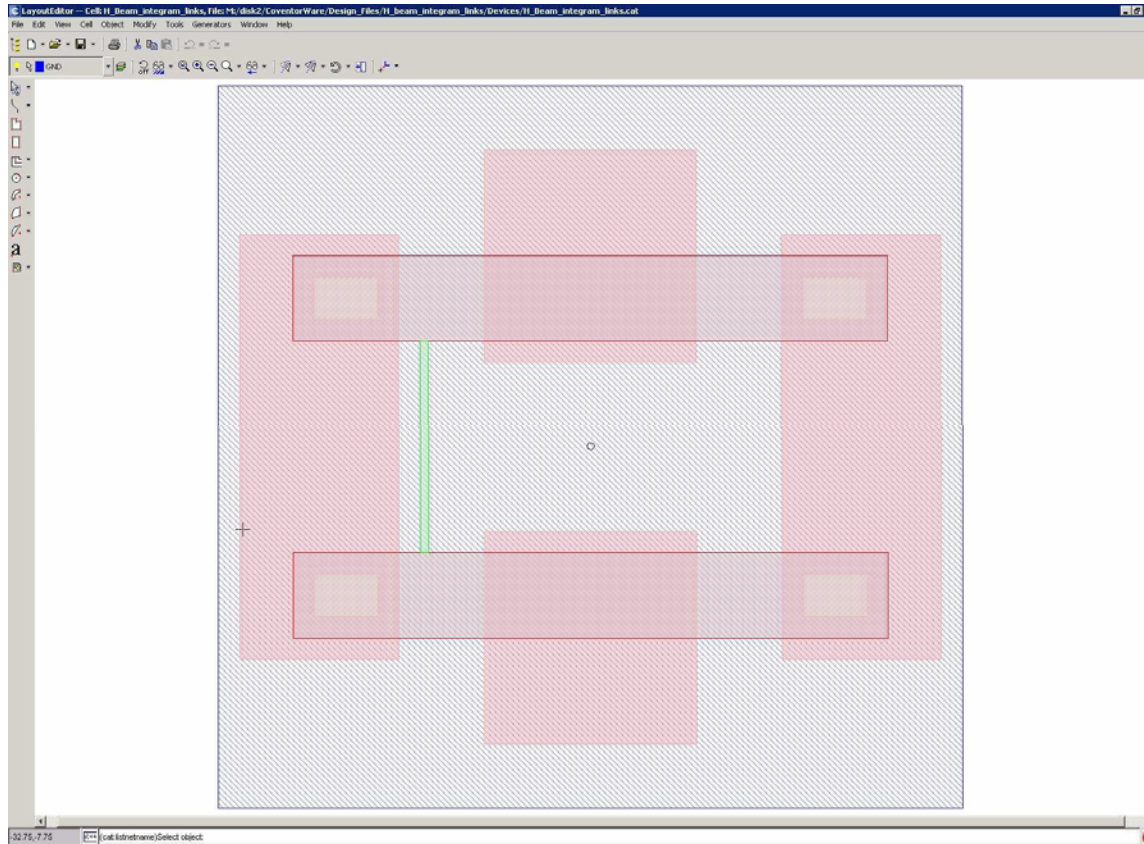
ACCELERATING
MEMS Innovations™

Process-description

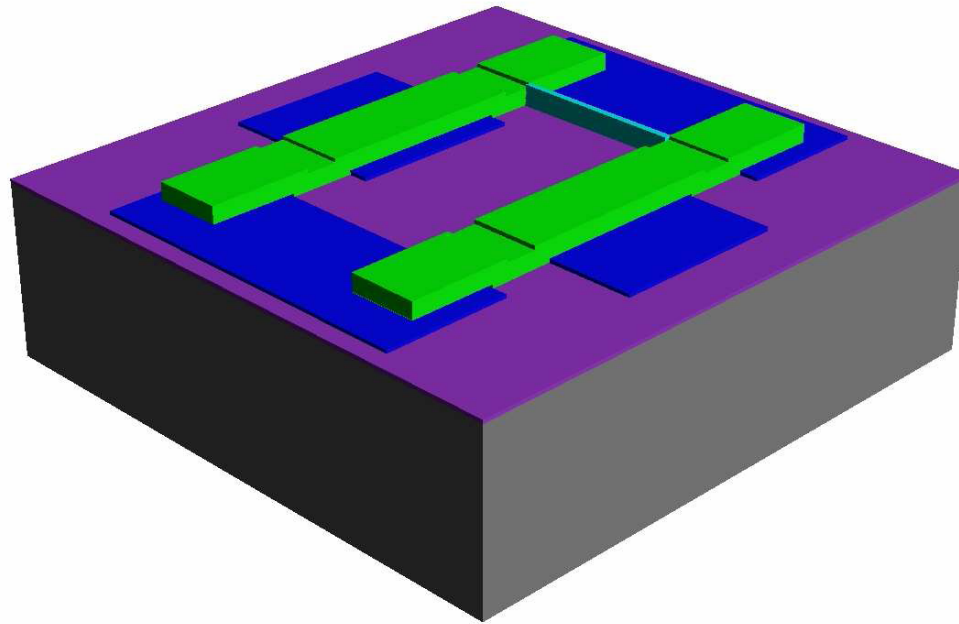
- Specify a **process file** compatible with the relevant “foundry” -process
 - Reduce complexity, idealization
 - Realistic: characteristic process features should be kept



Layout

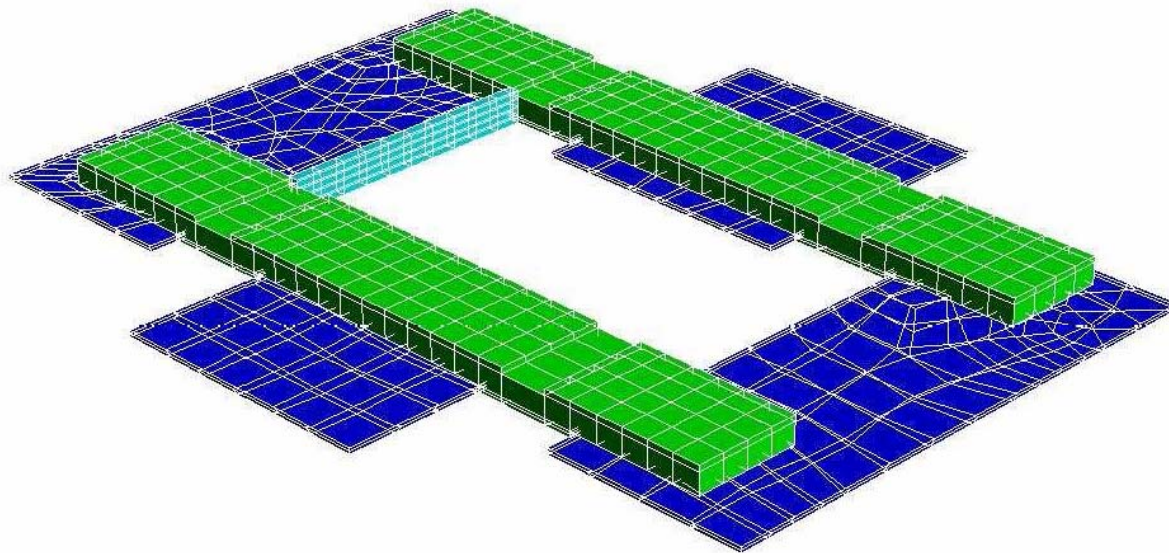


Building a 3-D model

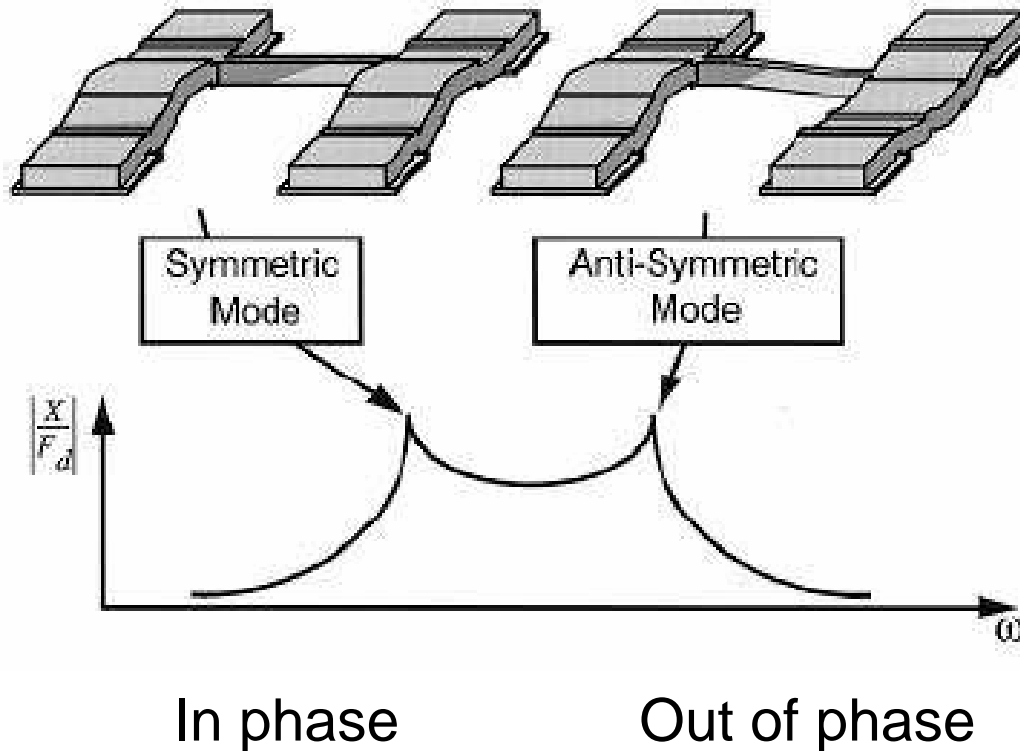


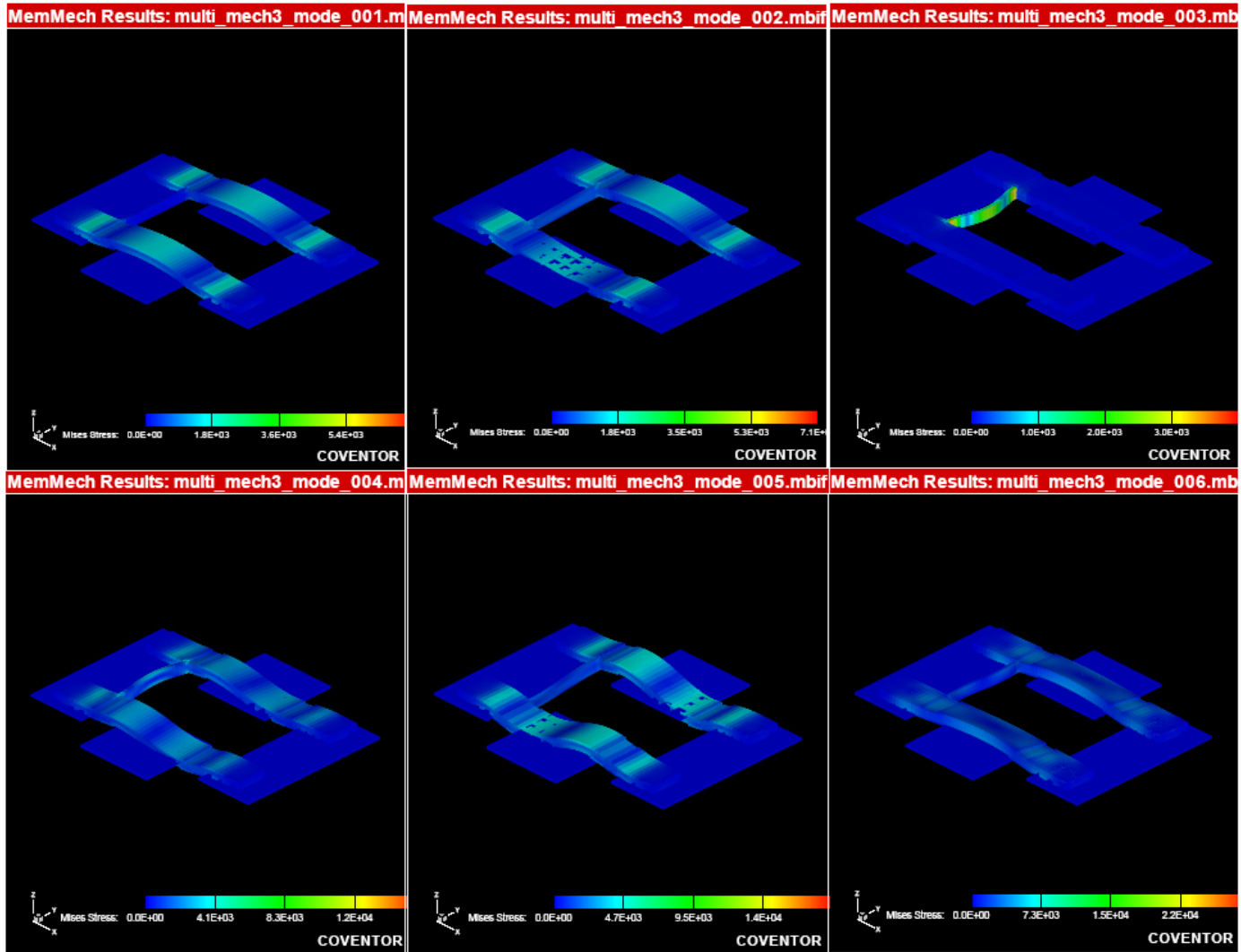
O-P Arhaug

Meshed 3D -model for FEM analysis



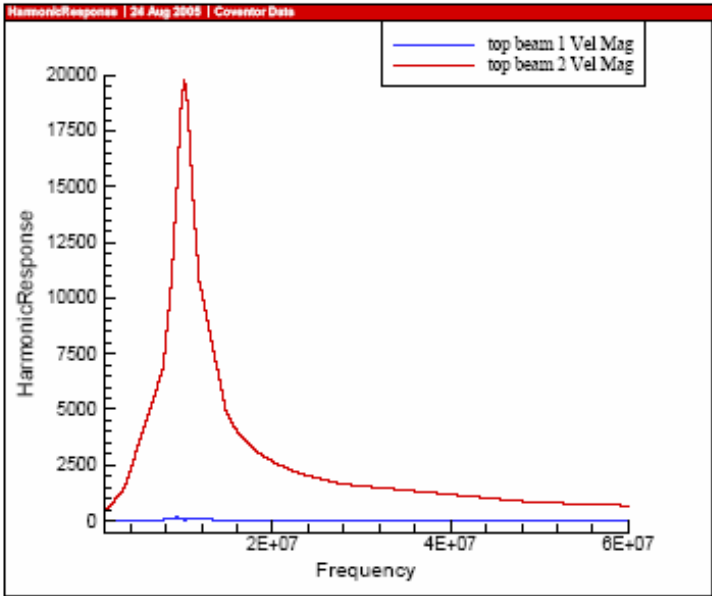
Filter-function: 2 identical resonators



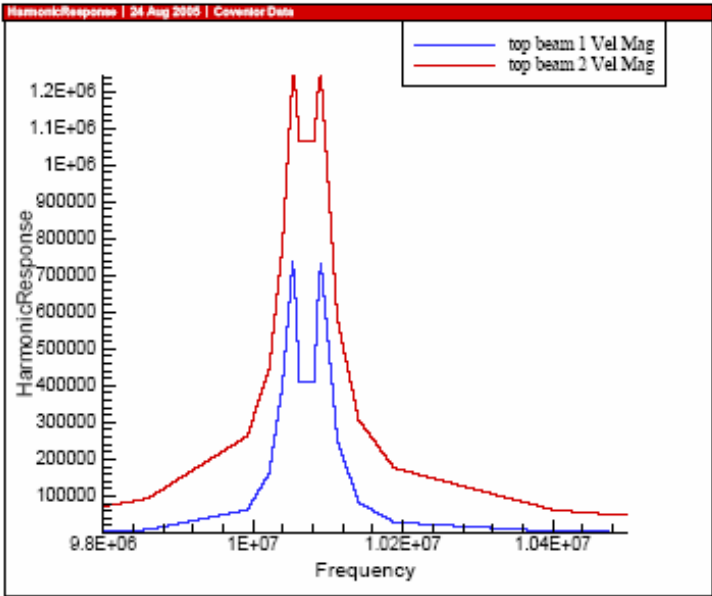


CoventorWare simulations for 6 resonating modes (O-P Arhaug)

Harmonic response for specific dampings



(a) 0,1



(b) 0,001

Exam

- Oral **exam** (45 min)
 - Option II: 3 hours written exam
 - Depending on the number of students
- Relevant exam questions will be posted on web later on
 - List for 2009 questions is available now!

Themes covered in the course

- RF MEMS is a **multi disciplinary** field
- **Main topics**
 - Introduction (1 week)
 - Micromachining (1 week)
 - Modeling (1 week)
 - RF circuit design (1 week)
 - Typical RF MEMS circuit elements (8 weeks)
 - Operation principles, models/analysis and examples
 - Switches, phase shifters, resonators, filters, capacitors and inductors
 - Packaging (1 week)
 - RF system design (1 week)
 - Repetition (1 week)

Literature

- Text book
 - Vijay K. Varadan, K.J. Vinoy, K.A. Jose, "*RF MEMS and their applications*". John Wiley, 2003. ISBN 0-470-84308-X
 - Supplementary: Ville Kaajakari: "*Practical MEMS*", Small Gear Publishing, 2009. ISBN: 978-0-9822991-0-4
 - No single book is particularly good
- Lecture notes (**IMPORTANT!**)
 - → Most of the syllabus is covered as lecture notes (ca. 1000)
 - Posted on web before lecture
- INF9490 version: Additional curriculum (to be defined)!
- Supporting literature?
 - Overview of literature given on the web course page, e.g.:
 - Gabriel M. Rebeiz, "*RF MEMS, Theory, Design, and Technology*". John Wiley, 2003. ISBN 0-471-20169-3
 - Stephen D. Senturia, "*Microsystem Design*", Kluwer Academic Publishers, 2001. ISBN 0-7923-7246-8

Contact information

- Responsible lecturer
 - Oddvar Søråsen, room 3411, phone: 22 85 24 56
 - oddvar@ifi.uio.no
- Responsible for groups/obliger/CoventorWare:
 - Dag Halfdan Bryn, room 3420
 - daghb@ifi.uio.no
- Contact person CoventorWare: support
 - Yngve Hafting, 5. floor Veilab, phone: 22 85 16 91
 - yngveha@ifi.uio.no
- web pages
 - <http://www.uio.no/studier/emner/matnat/ifi/INF5490/v10/>

Quality assurance

- Course assessor
 - Chief Scientist Geir Uri Jensen, SINTEF ICT, MiNaLab
- Quality assessment
 - The course coordinator is required to engage students in continuous **evaluation of the course**, offering the students an opportunity to provide continuous **feedback** on the quality of the course. Thus, the course coordinator can make **improvements** based on this feedback

“Institutt for informatikk ønsker en kontinuerlig evaluering av både form og innhold i undervisningen.

Evalueringen skal gi studentene ved et emne mulighet til å komme med tilbakemeldinger underveis, slik at eventuelle forbedringer kan gjøres umiddelbart.

I tillegg skal underveisevalueringen hjelpe faglærer og instituttet til å fange opp god og mindre god undervisningspraksis og heve kvaliteten på emnet/undervisningen.

Emneansvarlig lærer utformer evalueringsopplegget i samråd med studentene som følger emnet og er ansvarlig for kunngjøring av tidspunkt og gjennomføring. Omfang og evalueringsmetode tilpasses hvert enkelt emne og avgjøres av faglærer.

Faglærer utfører eventuelle forbedringer og kommuniserer resultatet til studentene.”

Today's lecture

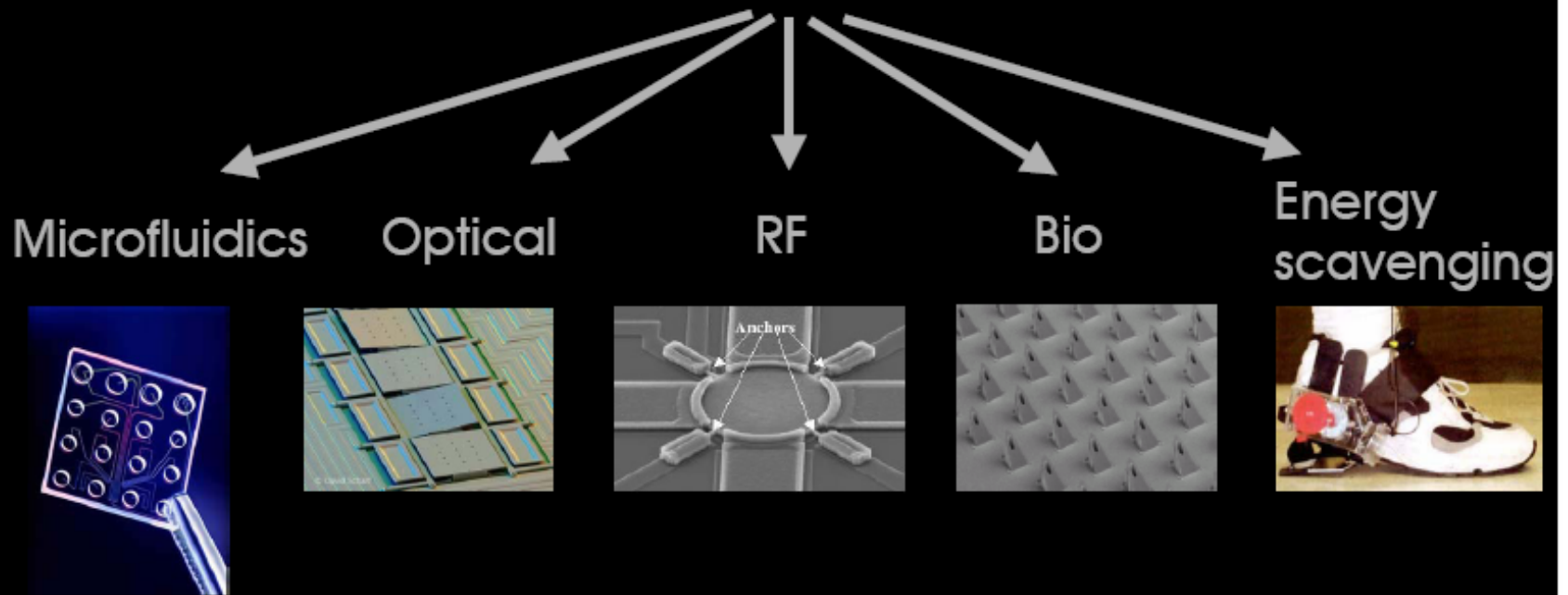
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Introduction to the topic RF MEMS

- Observe: **2 disciplines** involved: **RF** and **MEMS**
- **RF** – "Radio frequency"
 - High frequencies: MHz, GHz
 - Used in wireless transmission
 - Many characteristic, special properties related to **high frequency designs**
 - Course, Fall (Tor Fjeldly), **recommended!**
 - **INF5480 RF-circuits, theory and design**
 - Central/needed RF topics for INF5490 are covered in the current course

MEMS as enabling technology

MEMS = Micro-Electro-Mechanical Systems



Functionalities you cannot perform with pure electronic functions

The Technology is MEMS

- MEMS – Micro Electro Mechanical Systems
 - Microsystems
 - MST, Micro System Technology
 - → NEMS ("nano"...), MEM/NEM
- **Micromachining is basic!**
 - Further developments of IC fabrication (Silicon)
 - Various MEMS processes available today
 - Often proprietary, specialized for a product
 - Different from CMOS (restricted "second sourcing")
 - + other materials: plastic and organic materials (polymeres)
- General course on MEMS given by Liv Furuberg, SINTEF, in the fall semester, **recommended!**
 - FYS4230 Micro- and nanosystem modeling and design
 - Some central topics are covered in INF5490
- **MEMS is a promising technology for RF applications**

"Scaling" is fundamental

- Feature sizes measured in microns or less [Najafi, Michigan]

80 mm

Gimballed, Spinning Macro-Gyroscope

MEMS Technology (for 80X size Reduction)

Signal Conditioning Circuits

Vibrating Ring Gyroscope

1 mm

[Najafi, Michigan]

Micromechanical

[C. Nguyen]

MEMS in general

- 2 types of units: sensors and actuators
 - **Sensor:** (input)
 - "Feels"/ are influenced by environment
 - Movement is transformed to electrical signals
 - Many examples (pressure, acceleration)
 - The earliest applications (1980s)
 - **Actuator:** (output)
 - Movable structure controlled by electric circuit
 - Ex. Micro motor
 - Ex. Capacitor with movable plates

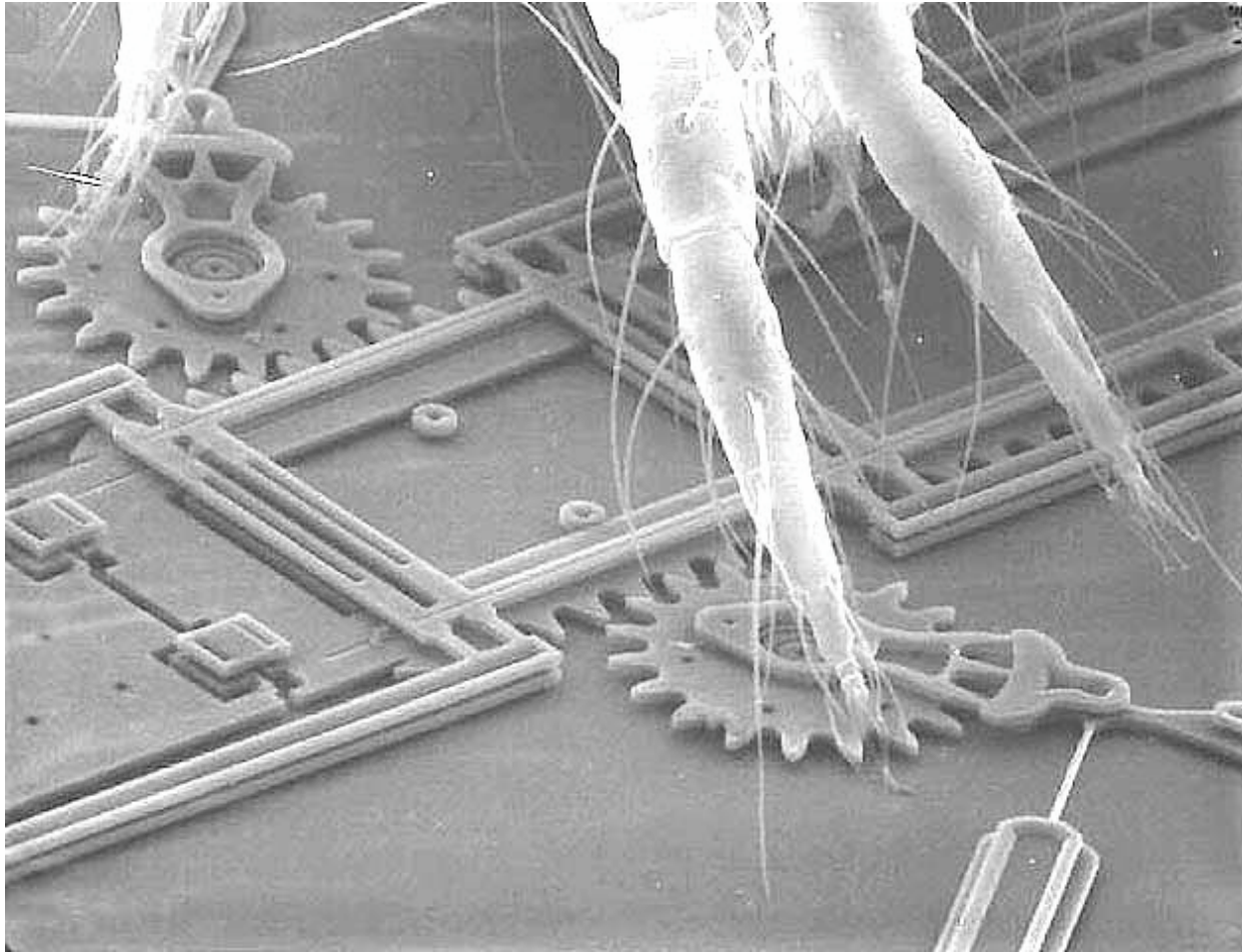
Actuation mechanisms

- MEMS structures can be actuated (= “moved”) **laterally** or **vertically**
- Actuation mechanisms (more in future lectures)
 - **Electrostatic**
 - Capacitor-structures: +/- charges attracted
 - Simple, low energy levels, enough for RF applications
 - **Thermal**
 - **Magnetic**
 - **Piezoelectric**
 - Strain (= “tøyning”) produces an electric field, - and opposite!

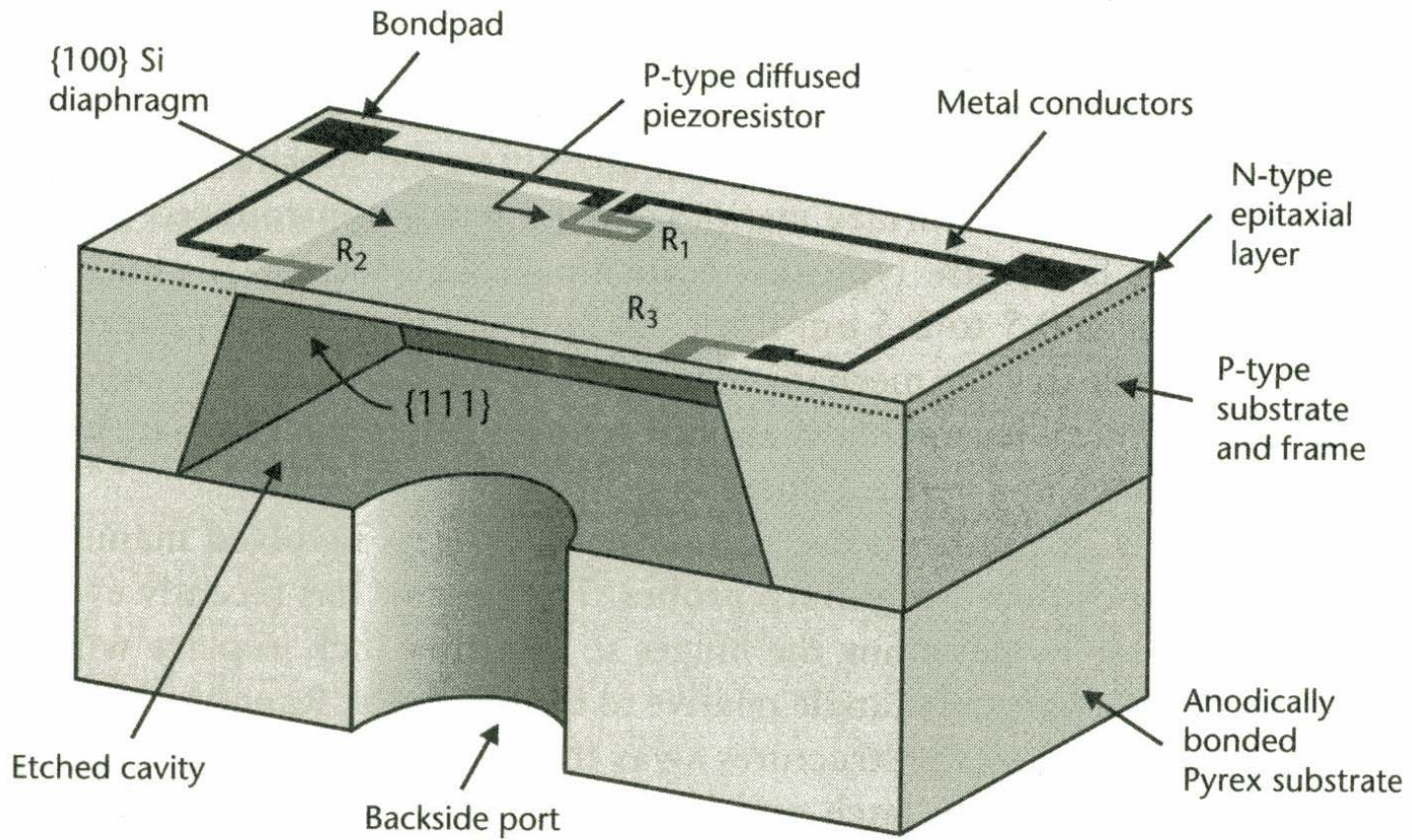
Some applications of MEMS

- **Automotive industry**
 - Micro accelerometers
 - Airbag-sensors (InfineonSensoNor)
 - Tire pressure sensors
- **Oil industry**
 - Pressure sensor in oil wells and oil tubes
- **Navigation**
 - Gyroscope
- **Biomedical**
 - Micro fluidic, chemical analysis
 - Implants
- **Optics**
 - Micro mirrors for projector, micro lenses for mobile phones
- **Computer industry**
 - Ink printer-head
- **Wireless communication**
 - RF MEMS switches

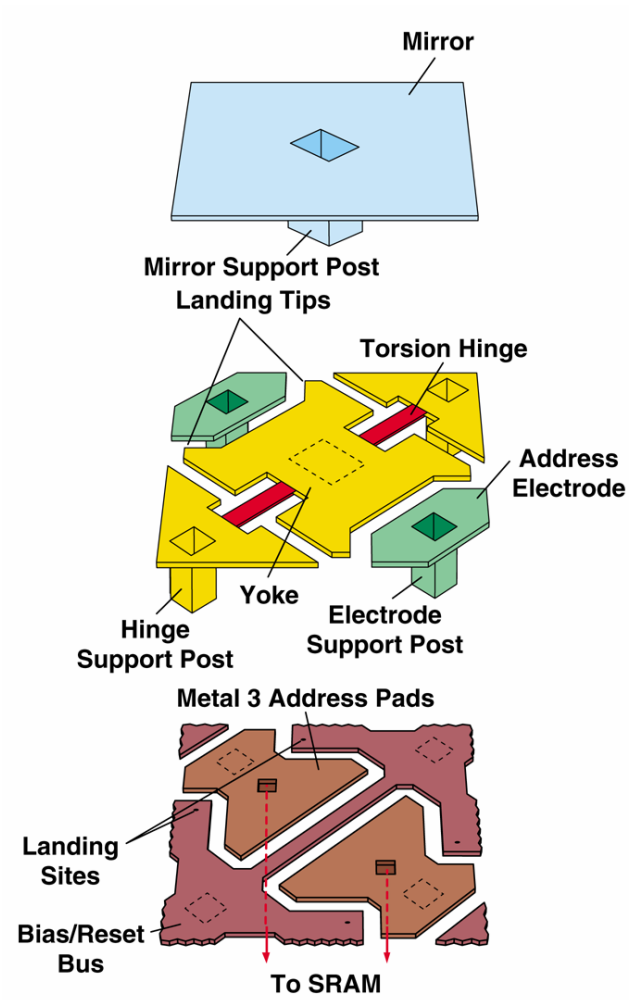
Micro motor fra Sandia



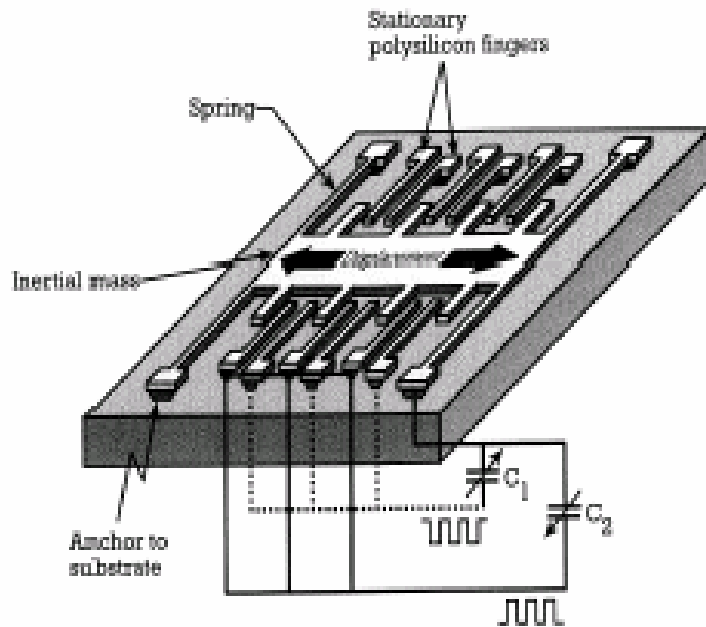
Pressure sensor



Micro mirror

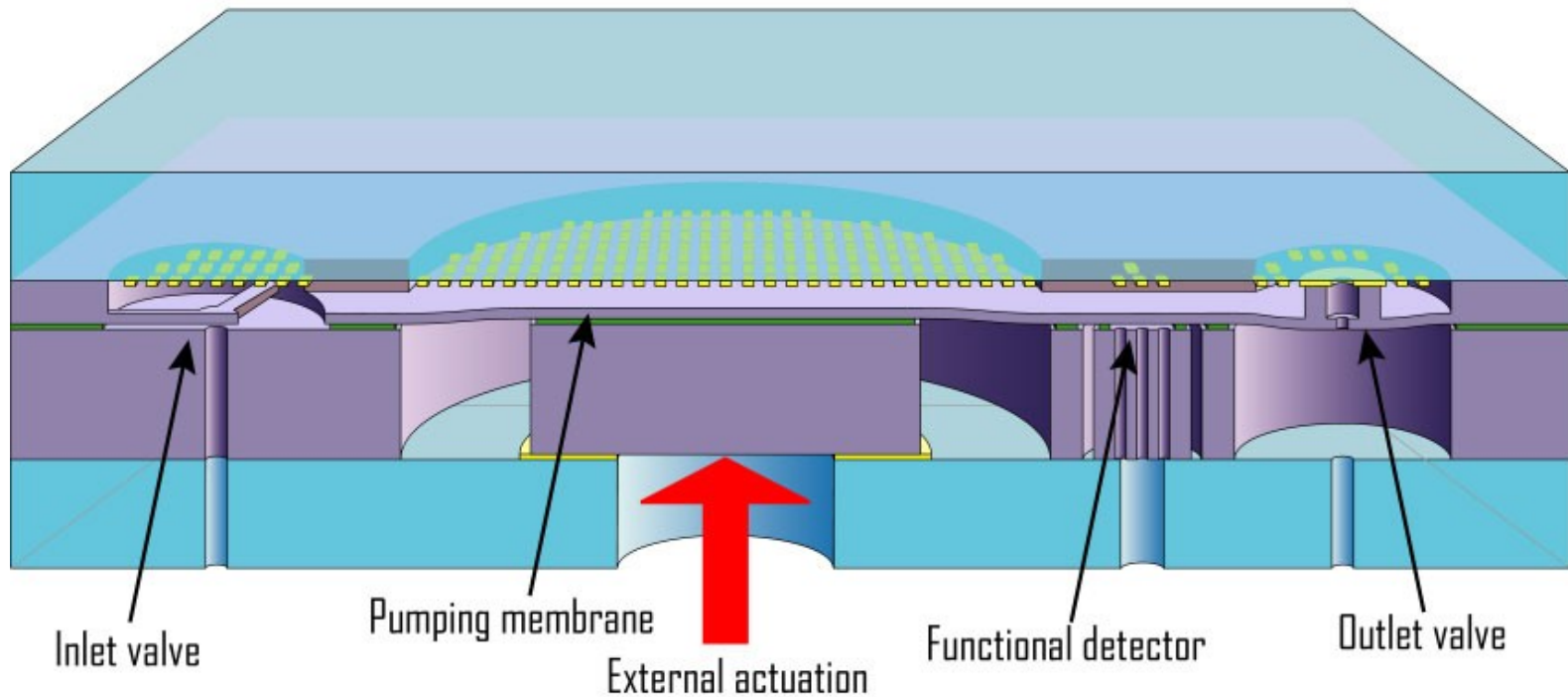


A Capacitive Accelerometer

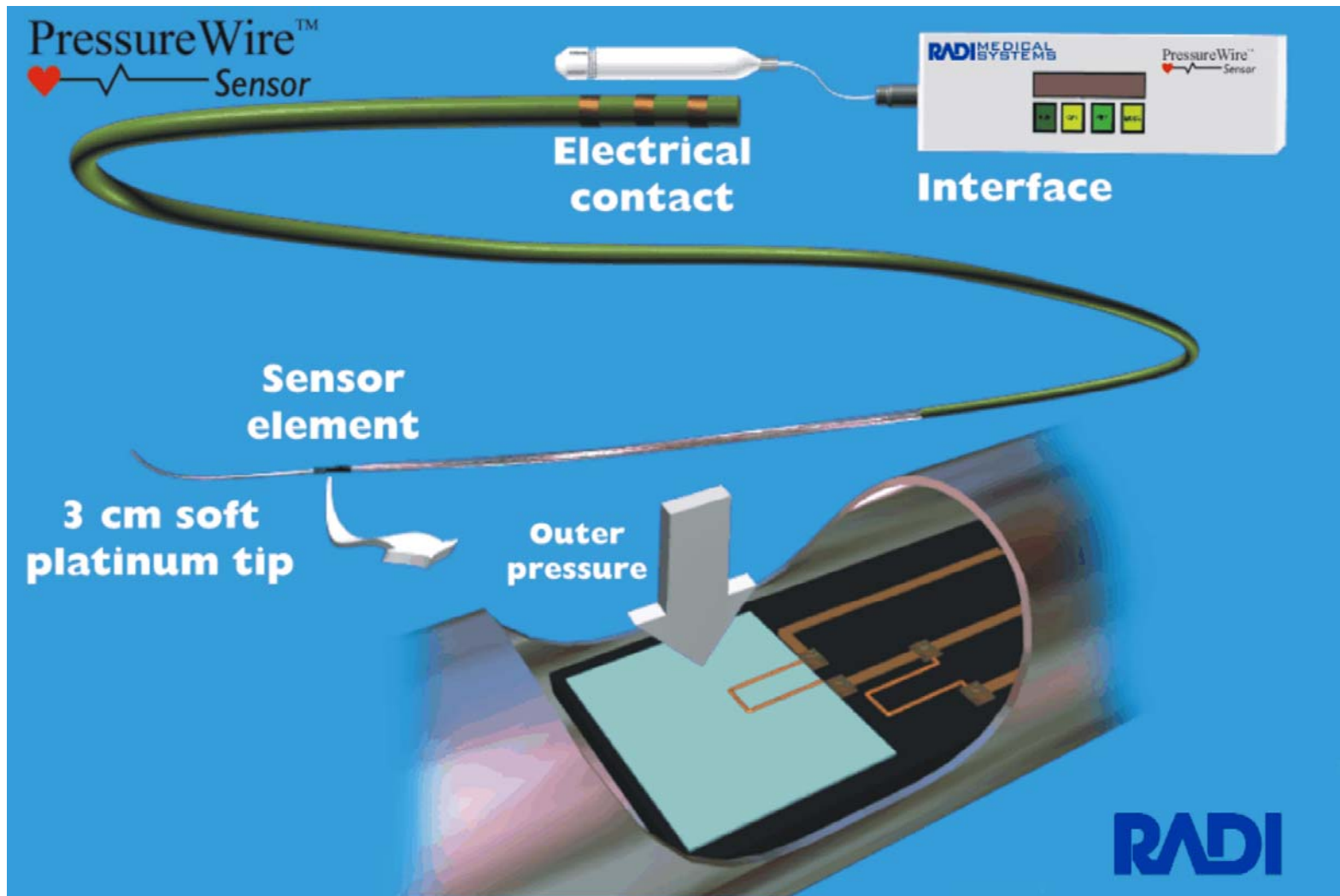


Technology Analysis: Drug Delivery

Debiotech Chip



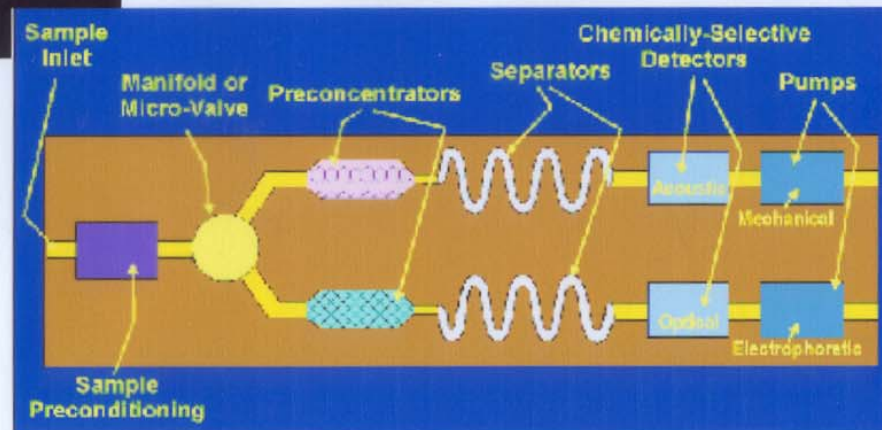
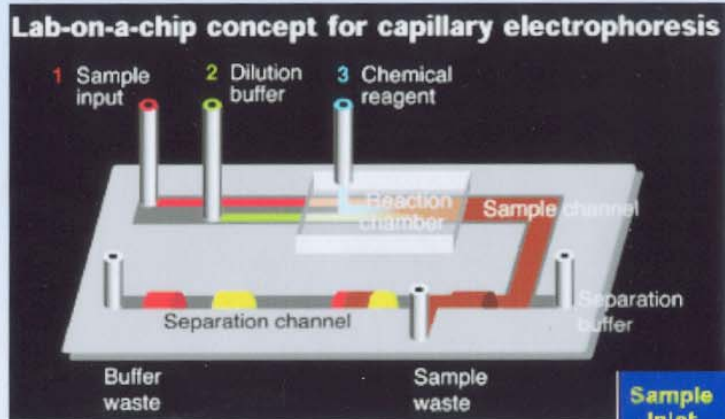
Radi Catheter



RADI

Biotechnology MEMS

“Lab-on-a-Chip”



iSTAT



- blood analysis
glucose, urea, pH, blood gases,
- portable POC device
- analyser + disposable cartridges
- microfluidic channels
- micro-fabricated thin-film electrodes

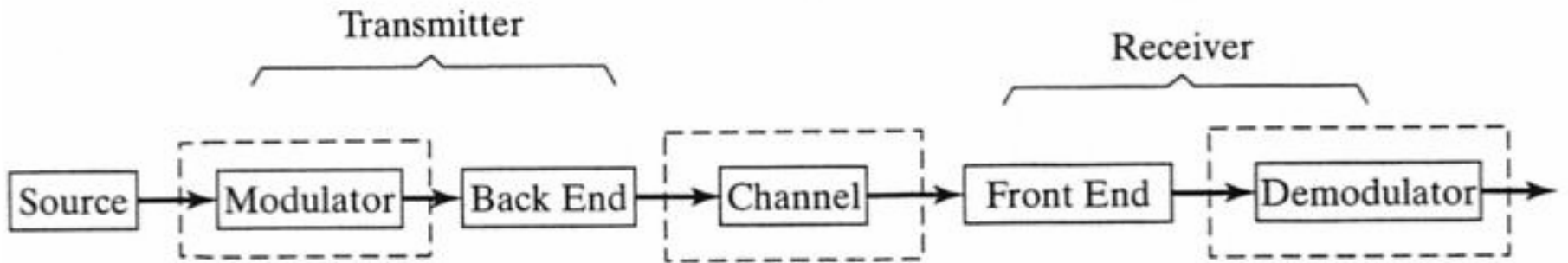
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RF-systems in general

- Radio waves are used for transmitting/receiving
 - Electromagnetic waves (Maxwells equations)
- Basic component: radio **"transceiver"**
 - Transmitter + Receiver
 - Methods for transmission
 - TDMA (Time Division Multiplexing Access)
 - FDMA (Frequency D M A)
- Signal quality depends on
 - Position
 - Environment, reflection
 - "Multipath"
 - Noise (S/N-ratio, BER= bit error rate)

General communication system



Carrier modulation to represent Bit flow

Radio channel introduces noise and interference

Receiver converts the signal before demodulation

→ **High performance components are required!**

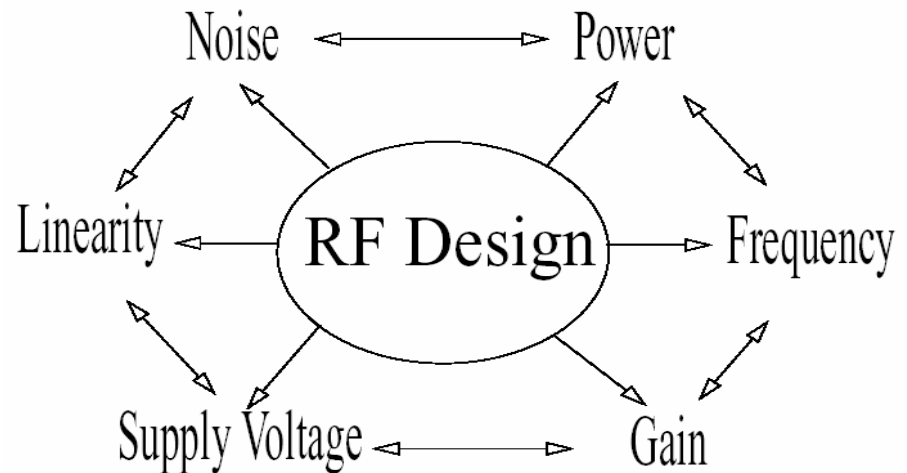
RF-systems

- Efficiency/performance of RF-systems
 - Ability to transfer **power**
 - Simultaneously use of limited **bandwidth**
- The frequency resource is limited
 - "Sharp" RF-filtering needed to separate channels
 - The quality and performance of the RF components are critical to implement wireless communication systems
 - **→ RF MEMS can meet critical requirements!**

RF design

- → **A major challenge for circuit designers!**
 - Many aspects have to be considered when doing RF design

RF Design Hexagon
Multi-objective approach



Jerzy Dabrowski, CMOS RF Transceiver Design, 2004

- CMOS-technology is a strong candidate for implementing critical parts of a transceiver!
 - **BUT not able to fulfill all requirements of component performance**

Implications of RF vs. circuit technology

- Increased frequency:

- → shorter wavelength

- in vacuum:

$$\lambda \cdot f = c$$

- → signal variations in short physical distances

- voltage V , current I are not constant over the component dimension: → waves!

- → smaller component dimensions are desired

- small tolerance fabrication

- micromachining

Table 1-1 IEEE Frequency Spectrum

Frequency Band	Frequency	Wavelength
ELF (Extreme Low Frequency)	30–300 Hz	10,000–1000 km
VF (Voice Frequency)	300–3000 Hz	1000–100 km
VLF (Very Low Frequency)	3–30 kHz	100–10 km
LF (Low Frequency)	30–300 kHz	10–1 km
MF (Medium Frequency)	300–3000 kHz	1–0.1 km
HF (High Frequency)	3–30 MHz	100–10 m
VHF (Very High Frequency)	30–300 MHz	10–1 m
UHF (Ultrahigh Frequency)	300–3000 MHz	100–10 cm
SHF (Superhigh Frequency)	3–30 GHz	10–1 cm
EHF (Extreme High Frequency)	30–300 GHz	1–0.1 cm
Decimillimeter	300–3000 GHz	1–0.1 mm
P Band	0.23–1 GHz	130–30 cm
L Band	1–2 GHz	30–15 cm
S Band	2–4 GHz	15–7.5 cm
C Band	4–8 GHz	7.5–3.75 cm
X Band	8–12.5 GHz	3.75–2.4 cm
Ku Band	12.5–18 GHz	2.4–1.67 cm
K Band	18–26.5 GHz	1.67–1.13 cm
Ka Band	26.5–40 GHz	1.13–0.75 cm
Millimeter wave	40–300 GHz	7.5–1 mm
Submillimeter wave	300–3000 GHz	1–0.1 mm

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MEMS in RF-systems

- RF MEMS development started in the 90s
 - 1990: the first MEMS microwave **switch** better than GaAs (Hughes Res Lab)
 - 1995: RF MEMS switches from Rockwell Science & TI
 - From 1998: some **universities** do research in RF MEMS
 - Univ of Michigan, Univ of Calif Berkeley, Northeastern Univ, MIT, Columbia Univ, CMU (Carnegie Mellon), etc.
 - Some relevant **companies**:
 - Analog Devices, Motorola, Samsung, ST Microelectronics
 - **Research institutes**
 - Sandia, Fraunhofer, IMEC, LETI, SINTEF

Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters

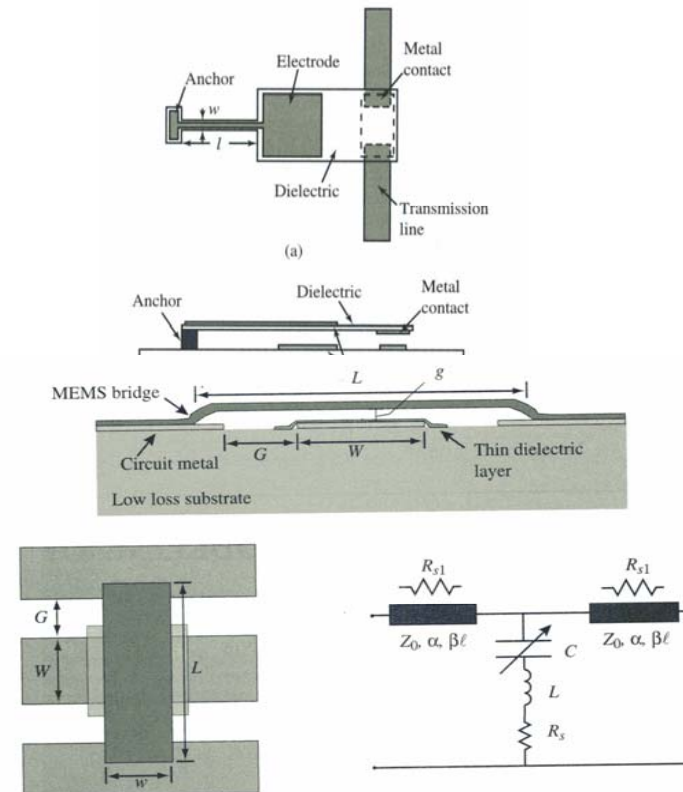
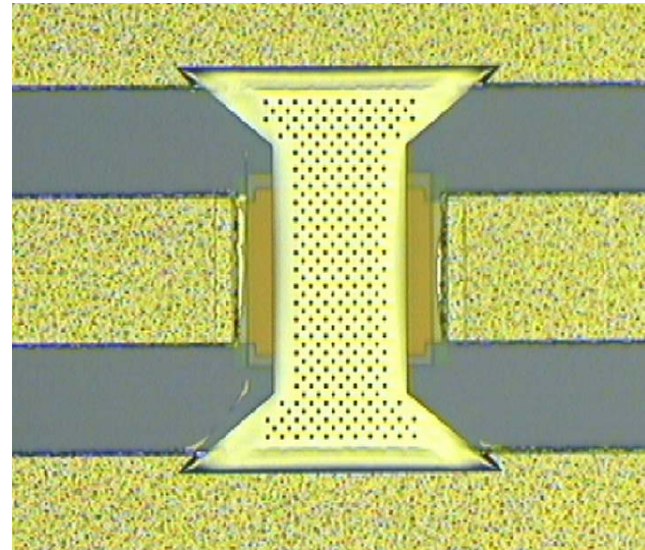


Figure 4.1. Illustration of a typical MEMS shunt switch shown in cross section and plan view. The equivalent circuit is also shown [6] (Copyright IEEE).

Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters

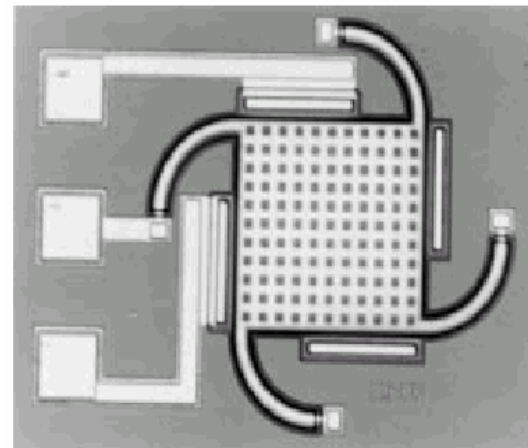
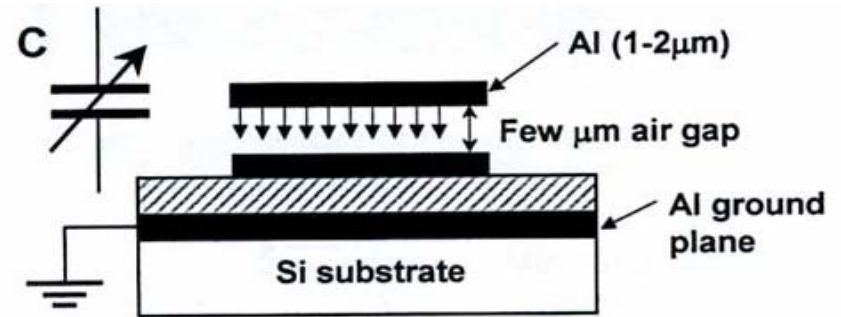


Ex.: microwave switch

- An early application of RF MEMS
 - Much activity, many examples exist
 - Benefits
 - **Electrostatic** actuation is typical: simple principle
 - El voltage → charge → attractive forces → mechanical movement
 - High signal linearity
 - Low DC "standby power"
 - Low loss ("insertion loss")
 - Challenges
 - Low switching speed (some μs)
 - Reliability of metal contacts (stiction, micro welding, wear-out)

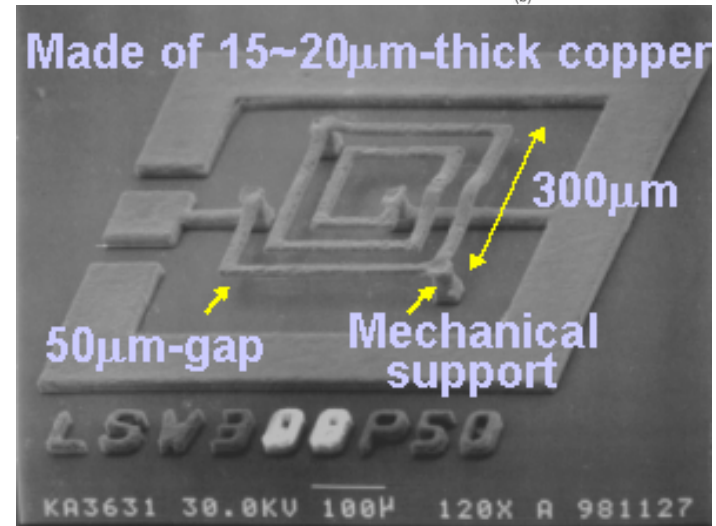
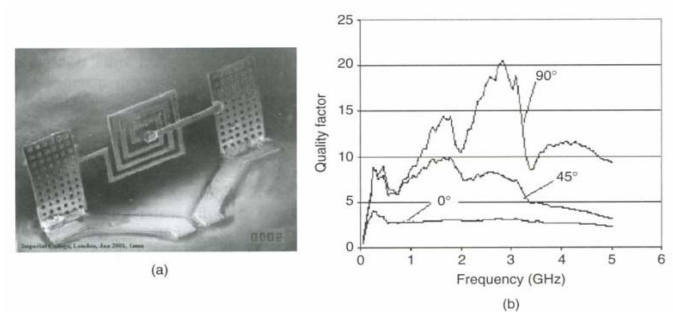
Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters



Typical RF MEMS components

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Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters
- MEMS also for:
transmission lines and
antennas

Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters
- **In INF5490: focus on real vibrating structures**
 - - Can be used to implement
 - **oscillators**
 - **filters**
 - **mixers**

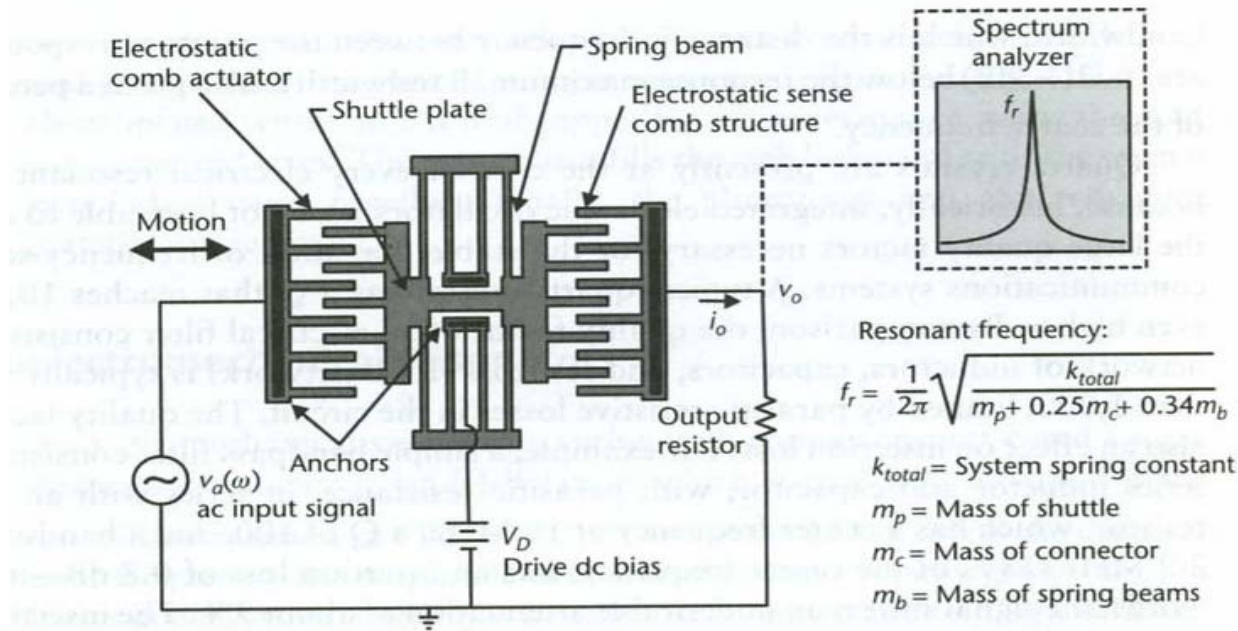
Micro-Electro-Mechanical resonators

High-Q with MEMS resonators: why?

- IC's cannot achieve Q's in the 1000's
 - transistors consume too much power to get Q
 - on-chip spiral inductors: $Q \sim$ low 10's
 - off-chip inductors: Q's in the range of 100's
- **Vibrating mechanical resonances $Q > 1000!$**
- Competitor: quartz crystal resonators (in wristwatches) have extremely high Q's $\sim 10^4 - 10^6$

Source: Clark Nguyen, ESSDERC 2007.

Comb-resonator



lateral (horizontal) movement

Clamped-clamped beam resonator

First-order
resonant frequency:

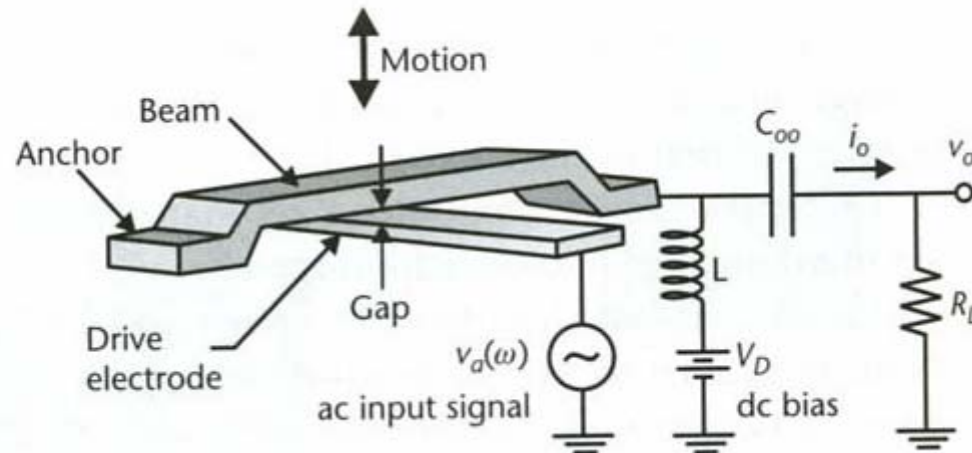
$$f_r = 1.03 \sqrt{\frac{E}{\rho}} \frac{t}{L^2}$$

E = Young's modulus

ρ = Density

t = Beam thickness

L = Beam length



Vertical movement

Benefits of RF MEMS

- Performance
- Power consumption
- Cost
- Miniaturization

Benefits of RF MEMS

- Higher **performance**
 - Increased selectivity: sharp filters
 - Increased Q-factor: stable "tank" frequency
 - Reduced loss
 - Higher isolation, reduced cross talk
 - Reduced signal distortion
 - Larger bandwidth
- Lower **power consumption**
- **Reduced cost**
 - Batch processing
- Circuit and system **miniaturization**
 - System integration (μ electronics + MEMS)
 - Packaging: Multi-chip module
 - Monolithic integration: SoC (System-on-Chip)

Challenges in RF transceiver implementation of today

- Performance
- Miniaturization
- Reconfigurability

Challenges in RF transceiver implementation of today

- **Performance**

- Integrated microelectronic components have **limited** RF performance
 - Technology: GaAs, bipolar Si, CMOS, PIN-diodes
 - ex. PIN-diode switch (inefficient), RF filter (difficult!)
- **Off-chip components in RF systems** are needed!
 - matching networks, filters
 - crystal oscillators, inductors, variable capacitors

- **Miniaturization**

- **Discrete, off-chip** components hinder miniaturization
- PCB → uses up a large space

Challenges in RF transceiver implementation of today

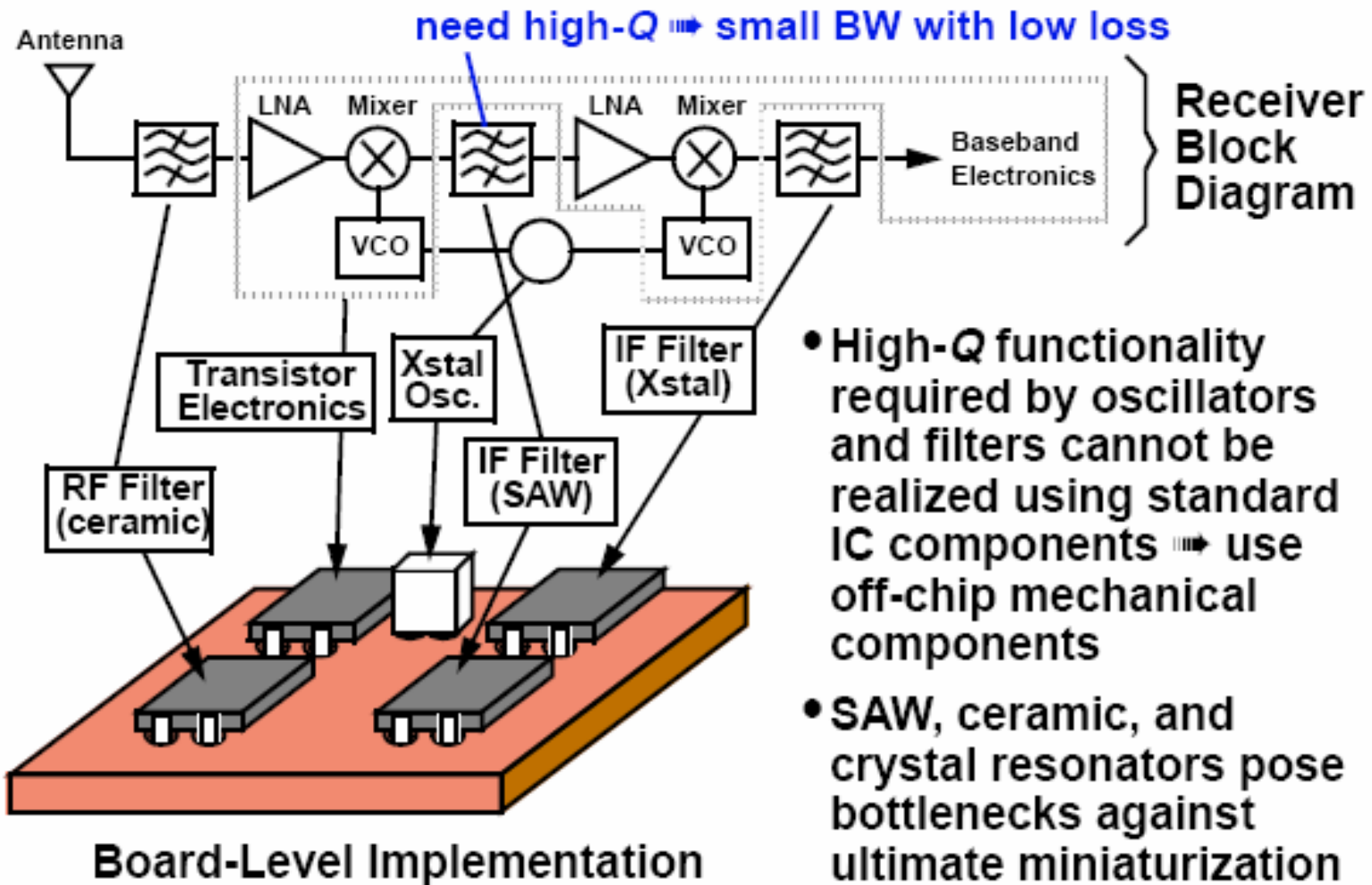
- **Reconfigurability**

- Increasing demands exist that one single RF transceiver shall cover various standards and channels
 - Programmability is desired
- **Reconfigurable "front-end"** for "sw defined radio"
 - RF MEMS may solve the problem!

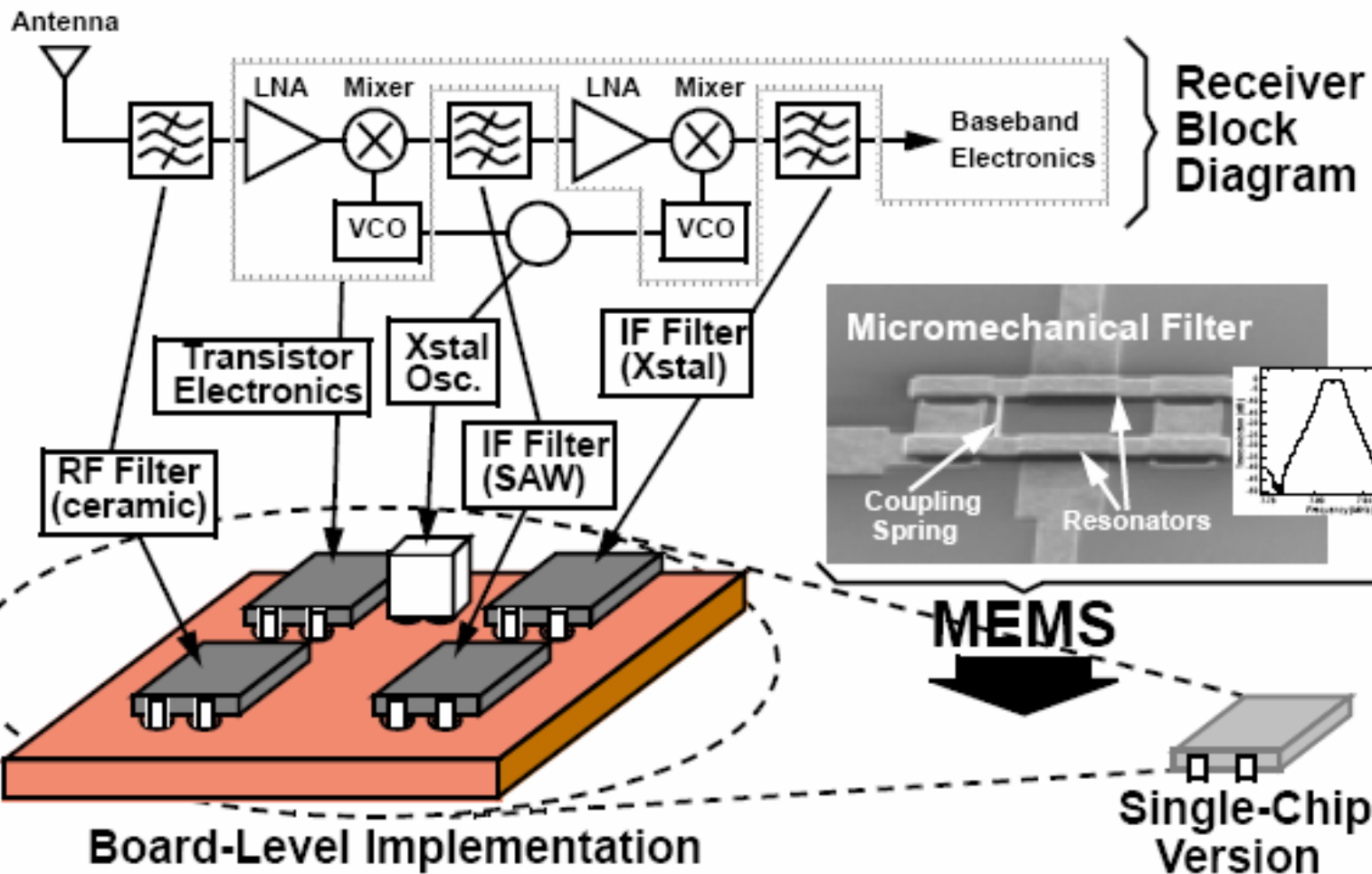
Use of RF MEMS

- A) **Replacing** discrete components
- B) **New** integrated functionality
 - New system architectures
 - Implement reconfigurable RF systems by using near ideal RF MEMS switches

Miniaturization of Transceivers

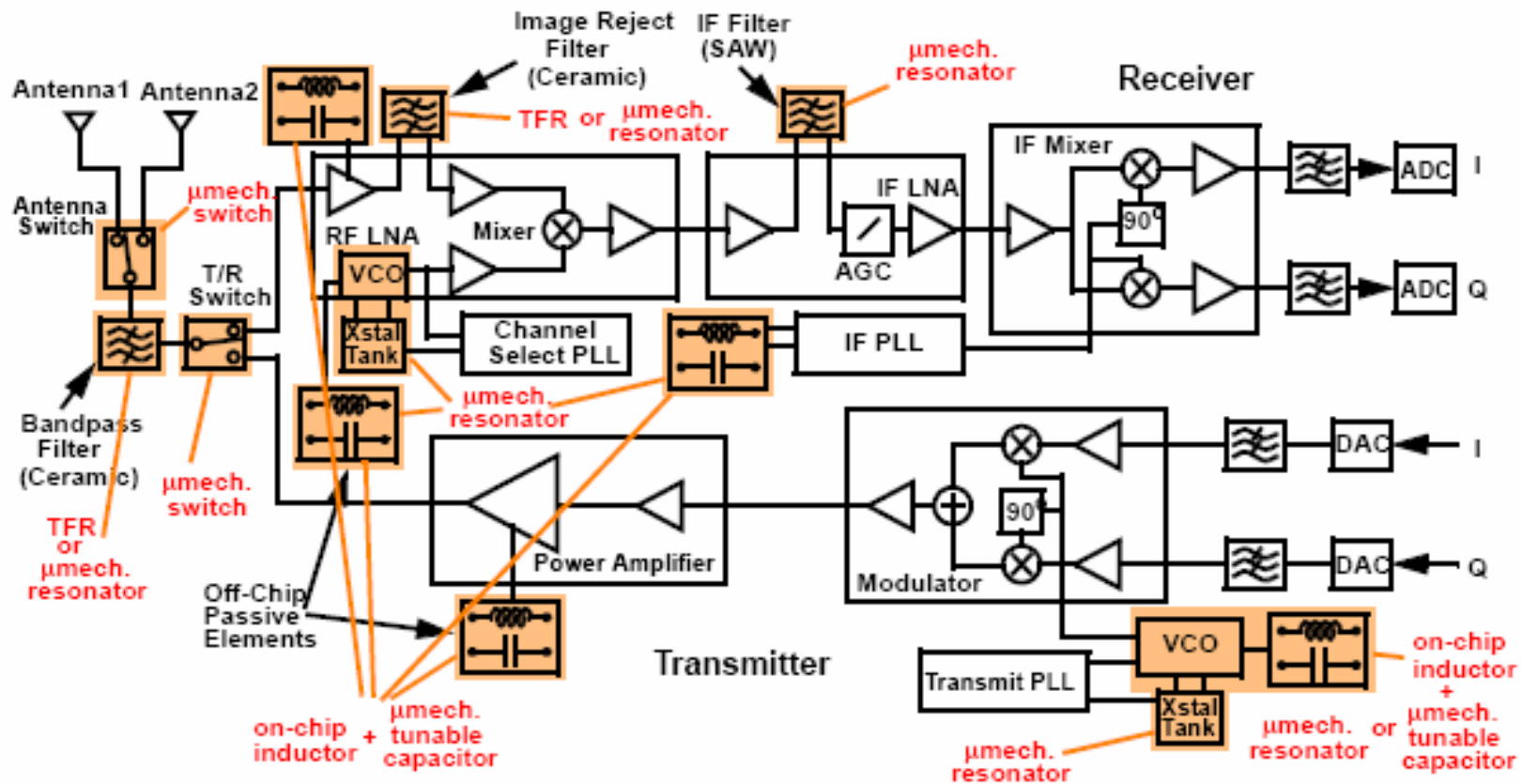


Target Application: Integrated Transceivers



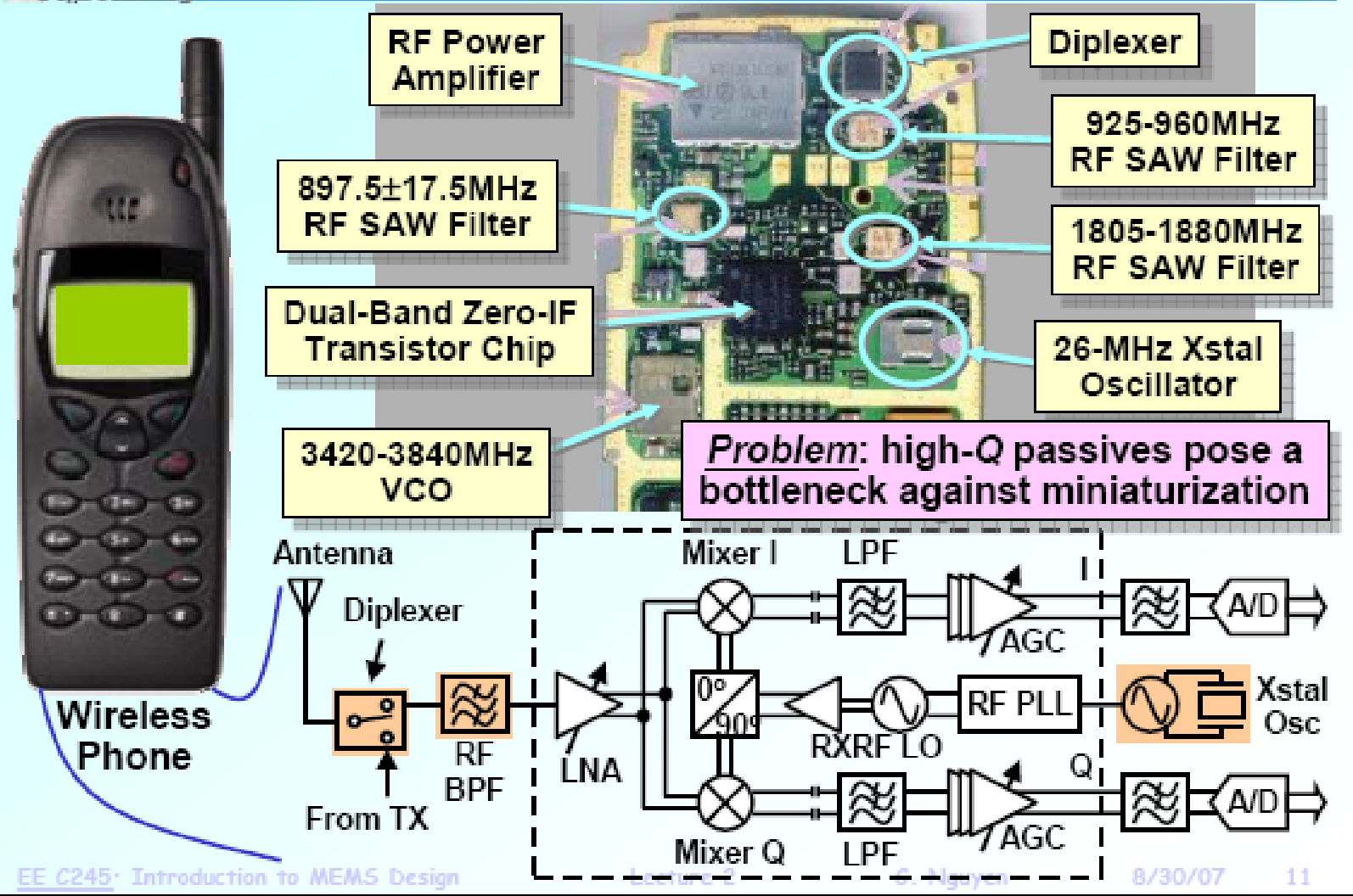
- Off-chip high-Q mechanical components present bottlenecks to miniaturization → replace them with μ mechanical versions

MEMS-Replaceable Transceiver Components



- A large number of off-chip high-Q components replaceable with μ machined versions; e.g., using μ machined resonators, switches, capacitors, and inductors

Miniaturization of RF Front Ends

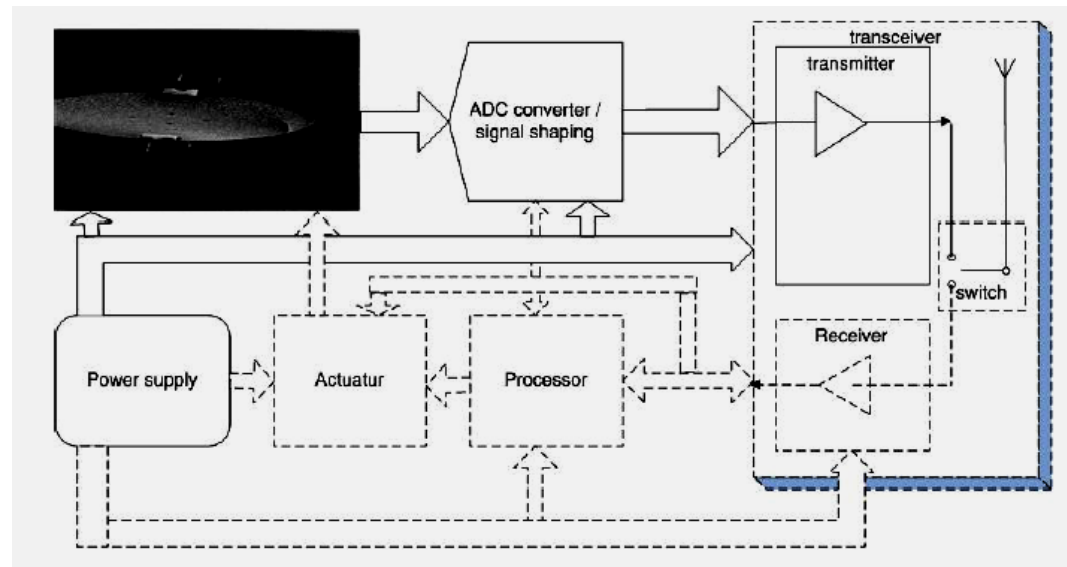
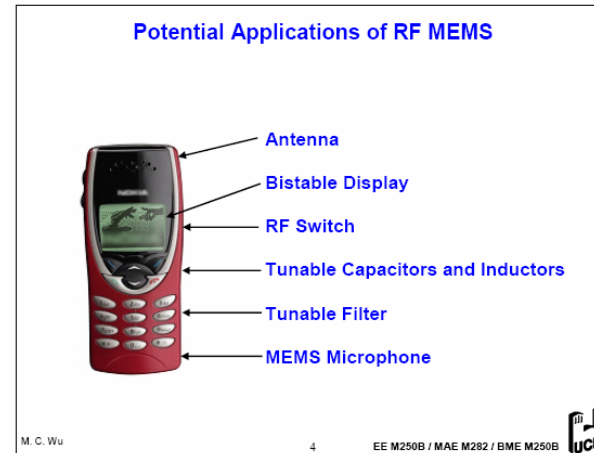


New RF architectures

- New ways to design RF systems
 - MEMS technology may be used to implement a lot of small, low cost basic modules
 - Switches may then be used to switch between the modules
 - MEMS makes it easier to perform module based design
 - Micromachined “lumped” (= “discrete”) components may replace distributed components
 - Enhanced system integration flexibility

Perspectives

- Use of wireless (personal) communication increases
 - 3-4 G systems
 - Mobile terminals
 - Multi-standard units
 - "15 radio systems in each unit?"
- Wireless sensor networks (WSNs)
 - Sensors everywhere
 - compact, intelligent
 - "ambient intelligence"



[J. Ekre]

Current challenges for RF MEMS

- Actuation **speed** needs to be increased
 - Switches (typical 1-100 μ s)
- Operating **RF frequency** needs to be increased for mechanical resonators and filters
 - Up to some GHz today (3 – 5 GHz)
- Good RF **filter banks** should be implemented
- Higher **reliability**
- **Packaging**
 - Vacuum
 - Modules of various materials and technologies
 - SiP – "System-in-Package"
- **Monolithic integration** is desired
 - SoC – System-on-Chip

Integrated solutions?

- Fabrication of microelectronics and MEMS have much in common
- Combination of electronics and micromechanics
 - Integrated solutions on a Si chip
 - → **”Radio-on-a-chip”!**
 - One option: CMOS-MEMS

MEMS for wireless integration

Intel Developer Forum Spring 2002

MEMS for wireless integration

Today

BASE BAND PROCESSOR RF CHIP

100s of passive components

Future (3 - 4 Yrs)

RF MEMS CHIP

BASE BAND RF

RF MEMS CHIP

Future (4+ Yrs)

BASE BANDS RF & MEMS CHIP

- Silicon integration follows Moore's law
- MEMS research to enable:
 - "High Value" passives (Filters, Switches etc) to be built from Silicon and integrated together

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